

## **JCWSCS** 0 9 MAR 2004

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### HAMILTON, BROOK, SMITH & REYNOLDS, P.C. 530 Virginia Road, P.O. Box 9133 Concord, MA 01742-9133

Telephone: (978) 341-0036

Facsimile: (978) 341-0136

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Examiner:

Andrew Q. Tran

Group:

2824

Date:

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From:

James M. Smith, Esq.

Subject:

Paper:

Second Request for Corrected Filing Receipt

Docket No.:

2037.1005-002

Applicant:

Peter B. Gillingham

Serial No.:

09/654,367

Filing Date:

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JMS/jat March 9, 2004 1978-341-0136

T-553 P.02/06 F-375

Docket No.: 2037.1005-002

### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Peter B. Gillingham

Application No.:

09/654, 367

Group:

2824

Filed:

September 1, 2000

Examiner:

Andrew Q. Tran

Confirmation No.:

8231

For:

METHOD OF MULTI-LEVEL STORAGE IN DRAM AND

APPARATUS THEREOF

CERTIFICATE OF MAILING OR TRANSMISSION

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# SECOND REQUEST FOR CORRECTED FILING RECEIPT FOR UTILITY APPLICATION

Office of Initial Patent Examination Customer Service Center Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

We hereby request that the following items of information be corrected in the Filing Receipt for the subject application received in this office on February 26, 2004.

The errors and corrections appear below.

09/654,367

-2-

### Continuing Data as Claimed by Applicant Section

This application is a REI of 08/595,020 01/31/1996 PAT R,E37,072 SHOULD READ AS FOLLOWS:

This application is a CON of REI 08/595,020 01/31/1996 PAT RE37,072, based on PAT 5,283,761.

Enclosed are a copy of the Filing Receipt with changes noted in red, and a copy of page 1 of the application as filed on September 1, 2000.

Pursuant to instructions in the February 29, 2000 O.G., we hereby request that the errors which are identified above be corrected in the captioned application to which this request for correction is directed. It is understood that the Patent Office will issue an automatically-generated, corrected Filing Receipt in this and, if applicable, any other affected applications.

Respectfully submitted,

HAMILTON, BROOK, SMITH & REYNOLDS, P.C.

James M. Smith

Registration No.: 28,043 Telephone: (978) 341-0036

Facsimile: (978) 341-0136

Date:





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From-HBS&R

CONFIRMATION NO. 8231 CORRECTED FILING RECEIPT OC000000011983932

Date Mailed: 02/26/2004

Receipt is acknowledged of this reissue Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Office of Initial Patent Examination's Filing Receipt Corrections, facsimile number 703-746-9195. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

Applicant(s)

Peter B. Gillingham, Kanata, ON, CANADA;

Domestic Priority data as claimed by applicant

This application is a REI of 08/695,020 01/31/1906 PAT R E37,072-

This application is a CON of REI 08/595,020 01/31/1996 PAT RE37,072, based on Foreign Applications PAT 5,283,761.

If Required, Foreign Filing License Granted: 02/03/2001

Projected Publication Date: None, application is not eligible for pre-grant publication

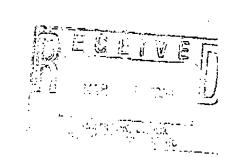
Non-Publication Request: No

Early Publication Request: No

Title

Method of multi-level storage in DRAM and apparatus thereof

**Preliminary Class** 



365

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### METHOD OF MULTI-LEVEL STORAGE IN DRAM

This is a continuation of Reissue Application Ser. No. 08/595,020, filed January 31, 1996, which is based on original U.S. Par. No. 5,283,761 issued February 1, 1994.

### FIELD OF THE INVENTION

This invention relates to dynamic random access memory (DRAM) memories, and in particular to a method of storing a variable level signal in each cell of a DRAM for representing more than one bit in each cell.

### BACKGROUND TO THE INVENTION

To store for example two bits in a DRAM cell, it must be able to store four different voltage levels. A problem with such cells, is that noise margins are reduced to one-third that of a one bit per cell DRAM, which is too low to withstand the occasional a-particle hit.

A second problem with multi-bit storage cells relates to the method of sensing. No sample method of sensing has previously been designed, although attempts have been made to solve this problem, e.g. as described in the publication by M. Aoli; et al. "A 16-Levels/Cell Dynamic Memory", ISSCC Dig. TECH. Papers 1985, pp. 246-247, and in T. Furuyama et al. "An Experimental Two-Bit/Cell Storage DRAM for Macrocell or Memory-On-Application", IEEE Journal of Solid State Circuits, Vol. 24, No. 2, pp 388-393, April 1989. The techmique described by Aoki cannot use normal sense amplifiers. It requires a precision analog D to A convener to implement a staircase waveform and a charge amplifier to sense data. The technique described by Furnyama requires the generation of precision reference levels to distinguish between four levels. These levels are not self-compensated for offsets developed in the sensing operation, and this method suffers from poor agnal margin. Hidaka et al describe a rechnique for simultaacously reading two cells at a time in the article "A divided/Shared Billine Sensing Scheme for 64Mb DRAM Core" in the 1990 Symposium on VLSI Circurry 1990, IEEE, p. 15, 16 which while describing dividing a hitline, is not related to multiple bit storage in a single cell.

DRAMs have previously been built with cells holding up to sixteen bits of storage, e.g. in the aforenoted article by M. Aoki et al, for use in file memories. A 4 K test array is believed to have been the largest memory built using this design. Leakage characteristics of the DRAM cell were required to be very tightly controlled and even then, accurate sensing of the small voltage differences between levels becomes very difficult. Another problem with this scheme was the length of time required to access: a single read cycle required 16 clocks for the read followed by 16 clocks for the restore.

To implement a 2 bit DRAM, one can define the cell as storing one of four voltage levels  $V_{cell}$ .  $V_{cell}$ .  $V_{cell}$ , and reference voltage midpoints between these four voltage, which can be defined as  $V_{rel}$ .  $V_{rel}$  and  $V_{rel}$ . These midpoints can be referred to, to differentiate between the four voltage levels. The relative voltage of these levels are shown in Table 1 below.

STORAGE VOLTAGES	RÉFERÈNCE VOLTAGES	ACTUAL VOLTAGE		
V <sub>cctll</sub>		VDD		
Veril	V <sub>M</sub> JS	5/6 V <i>DD</i> 2/3 V <i>DD</i>		